Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	4	(("5106778") or ("5612563")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/04/12 08:49
S2	2	"20020001905"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/12 13:05
S3	3	"09/669212"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/12 13:48
S4 .	9300	((inverter adj circuit) near15 transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/12 13:58
S5	4555	(438/763,761,758).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/04/12 14:12
S8	5	S5 and S6 and S7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/12 14:15
S7	129163	conductive and insulator	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/12 14:15
S6	15299	carbon near10 nanotube	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/12 15:55

S9	551	(carbon NEAR3 nanotube) NEAR5 insulat\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/12 15:56
S10	1	S9 and S5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/12 15:57
S11	128	S9 and "257"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/12 15:58
S12	2	(US-20010023986-\$ or US-20010019279-\$).did.	US-PGPUB	OR	·ON	2007/04/13 08:35
S16	256	(carbon NEAR3 nanotube) NEAR5 transistor and vertical	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/13 09:22
S15	1	S14 and S13	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/13 09:22
S14	551	(carbon NEAR3 nanotube) NEAR5 insulat\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/13 09:22
S13	4555	(438/763,761,758).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/04/13 09:22
S18	57	(carbon NEAR3 nanotube) same transistor near5 vertical	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/13 09:23

S17	. 57	(carbon NEAR3 nanotube) NEAR5 transistor near5 vertical	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/13 09:23
S20	32	S19 not S18	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/13 09:24
S19	89	(carbon NEAR3 nanotube) same transistor same vertical	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/13 09:24
S21	76	(carbon same nanotube same transistor same vertical) and insulat\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/13 09:26
S22	788	(gate near2 insulat\$3) and (carbon NEAR3 nanotube)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/13 09:27
S23	671	fet with nano\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/22 08:15
S26	30	("20010023986"   "20020020841"   "20020130311"   "6038060"   "6340822"   "6359288"   "6459095"   "6465813"   "6472705").PN. OR ("6566704"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/10/22 08:30
S25	. 2	("6566704").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/22 08:30

S24	37	"6566704"	US-PGPUB; USPAT; USOCR; EPO; JPO;	OR	ON	2007/10/22 08:30
		·	EPO; JPO; DERWENT; IBM_TDB			